10MHz, RRIO, CMOS Operational Amplifier for Cost-Sensitive Systems

General Description

ET85602 is a dual low-voltage (1.8 V to 5.5 V) operational amplifier (op amp) with rail-to-rail input- and output-swing capabilities. The device is highly cost-effective solutions for applications where low-voltage operation, a small footprint, and high capacitive load drive are required. Although the capacitive load drive of the ET85602 is 100 pF, the resistive open-loop output impedance makes stabilizing with higher capacitive loads simpler. The op amp is designed specifically for low-voltage operation (1.8 V to 5.5 V).

ET85602 is specified for the extended industrial/automotive temperature range (-40°C to +125°C). It is available in TSOT23-8 / SOP8 / MSOP8 packages.

Features

- Rail-to-rail input and output
- Low input offset voltage: ±0.3 mV
- Unity-gain bandwidth: 10 MHz
- Low broadband noise: 10 nV/$\sqrt{Hz}$
- Low input bias current: ±1 pA
- Low quiescent current: 550 μA
- Unity-gain stable
- Internal RFI and EMI filter
- Operational supply voltage range 1.8 V to 5.5V
- Easier to stabilize with higher capacitive load due to resistive open-loop output impedance
- Extended temperature range: -40°C to 125°C

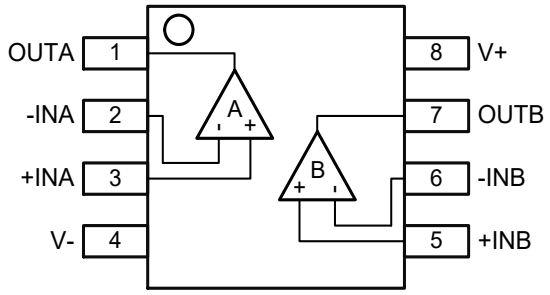
Applications

- Temperature sensors
- Smoke detectors
- Wearable devices
- Laptop computers
- Sensor signal conditioning
- Power modules
- Active filters
- Low-side current sensing

Device information

Part No.	Package	Tape / Reel
ET85602M	SOP8	Tape and Reel 4K
ET85602U	MSOP8	Tape and Reel 4K
ET85602E	TSOT23-8	Tape and Reel 3K

Pin Configuration



Top View

Pin Function

Pin Number ET85602M/U/E	Symbol	Descriptions
1,7	OUT	Output
4	V-	Negative supply
3,5	+IN	Non-inverting input
2,6	-IN	Inverting input
8	V+	Positive supply

Functional Description

Operating Voltage

ET85602 operates from 1.8 V to 5.5 V, is unity-gain stable, and is designed for a wide range of general-purpose applications.

Rail-to-Rail Input

The input common-mode voltage range extends 100 mV beyond the supply rails for the full supply voltage range of 1.8 V to 5.5 V. This performance is achieved with a complementary input stage.

Rail-to-Rail Output

Designed as a low-power, low-voltage operational amplifier, the ET85602 delivers a robust output drive capability. A class AB output stage with common-source transistors achieves full rail-to-rail output swing capability. For resistive loads of 10 kΩ, the output swings to within 15 mV of either supply rail, regardless of the applied power-supply voltage. Different load conditions change the ability of the amplifier to swing close to the rails.

Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are only stress ratings, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions are not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Parameter	Rating	Unit
Supply Voltage(V+) - (V-)	0~6	V
Common-mode Input Voltage(1)	(V-)-0.5V to (V+)+0.5	V
Differential Input Voltage(1)	(V+) - (V-)+0.2	V
Signal input pins Current(1)	-10~10	mA
Output short-circuit(2)	Continuous	mA
ESD (Human Body Model)	±2500	V
Storage Temperature Range	-65 to +150	°C
Max Junction Temperature Range	+150	°C

Note1:Input pins are diode-clamped to the power-supply rails. Current limit input signals that can swing more than 0.5 V beyond the supply rails to 10 mA or less.

Note2:Short-circuit to ground, one amplifier per package.

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
$R_{\theta JA}$	SOP8	Thermal Characteristics, Thermal Resistance, Junction-to-Air	160	°C/W
	MSOP8		200	°C/W
	TSOT23-8		185	°C/W

Recommended Operating Conditions

Parameter	MIN	MAX	Unit
Supply Voltage (V_S)	1.8	5.5	V
Operating Temperature Range (T_A)	-40	125	°C

Electrical Characteristics

V_S = (V+) – (V-) = 1.8 V to 5.5 V (±0.9 V to ±2.75 V), T_A = 25°C, R_L = 10 kΩ connected to V_S/2, and V_{CM} = V_{OUT} = V_S/2 (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OFFSET VOLTAGE						
V_{OS}	Input offset voltage	V_S = 5 V		±0.3	±1.6	mV
		V_S = 5 V, T_A = -40°C to 125°C			±2	
dV_{OS}/dT	V_{OS} vs temperature	V_S = 5 V, T_A = -40°C to 125°C		±0.53		µV/°C
PSRR	Power-supply rejection ratio	V_S = 1.8 to 5.5 V, V_{CM} = (V-)		±7	±80	µV/V
INPUT VOLTAGE RANGE						
V_{CM}	Common-mode voltage range	VS = 1.8 V to 5.5 V	(V-)-0.1		(V+)+0.1	V
CMRR	Common-mode rejection ratio	V_S = 5.5 V, (V-) - 0.1 V < V_{CM}< (V+) - 1.4 V, T_A = –40°C to 125°C		103		dB
		V_S = 5.5 V, VCM = –0.1 V to 5.6 V, T_A = -40°C to 125°C		87		
		V_S = 1.8 V, (V–) – 0.1 V < VCM < (V+) – 1.4 V, T_A = -40°C to 125°C		88		
		V_S = 1.8 V, VCM = –0.1 V to 1.9 V, T_A = -40°C to 125°C		81		
INPUT BIAS CURRENT						
I_B	Input bias current	V_S = 5 V		±1		pA
I_{OS}	Input offset current			±1		pA
NOISE						
E_n	Input voltage noise (peak to peak)	f = 0.1 Hz to 10 Hz, V_S = 5 V		4.77		μV_{PP}
e_n	Input voltage noise density	f = 1 kHz, V_S = 5 V		16		nV/√Hz
		f = 10 kHz, V_S = 5 V		10		
i_n	Input current noise density[3]	f = 1 kHz, V_S = 5 V		23		fA/√Hz
INPUT CAPACITANCE						
C_{ID}	Differential[3]			2		pF
C_{IC}	Common-mode[3]			4		pF

Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
OPEN-LOOP GAIN						
A_{OL}	Open-loop voltage gain	V_S = 1.8 V, R_L = 10 kΩ (V-) + 0.04 V < V_O< (V+) - 0.04 V		100		dB
		V_S = 5.5 V, R_L = 10 kΩ (V-) + 0.05 V < V_O< (V+) - 0.05 V	104	130		
		V_S = 1.8 V, R_L = 2 kΩ (V-) + 0.06 V < V_O< (V+) - 0.06 V		100		
		V_S = 5.5 V, R_L = 2 kΩ (V-) + 0.15 V < V_O< (V+) – 0.15 V		130		
FREQUENCY RESPONSE						
GBW	Gain-bandwidth product	V_S = 5 V, G =+1		10		MHz
φ_m	Phase margin	V_S = 5 V, G =+1		55		°
SR	Slew rate	V_S = 5 V, G =+1		6		V/μs
t_S	Settling time[(3)]	To 0.1%, V_S = 5 V, 2V step, G = +1, C_L = 100 pF		0.5		μs
		To 0.01%, V_S = 5 V, 2V step, G = +1, C_L = 100 pF		1		
t_{OR}	Overload recovery time	V_S = 5 V, V_{IN} × gain > V_S		0.2		μs
THD+N	Total harmonic distortion + noise	V_S = 5.5 V, V_{CM} = 2.5 V, V_O = 1 V_{RMS}, G = +1, f = 1 kHz,		0.0008		%
OUTPUT						
V_O	Voltage output swing from supply rails	V_S = 5.5 V, R_L = 10 kΩ			20	mV
		V_S = 5.5 V, R_L = 2 kΩ			60	
I_{SC}	Short-circuit current	V_S = 5 V		±50		mA
Z_O	Open-loop output impedance[(3)]	V_S = 5 V, f = 10MHz		100		Ω
POWER SUPPLY						
V_S	Specified voltage range		1.8 (±0.9)		5.5 (±2.75)	V
I_Q	Quiescent current per amplifier	I_O = 0 mA, V_S = 5.5 V		550	750	μA
		I_O = 0 mA, V_S = 5.5 V, T_A = -40°C to 125°C			800	

Note3:Guaranteed by design.

Application Notes

Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

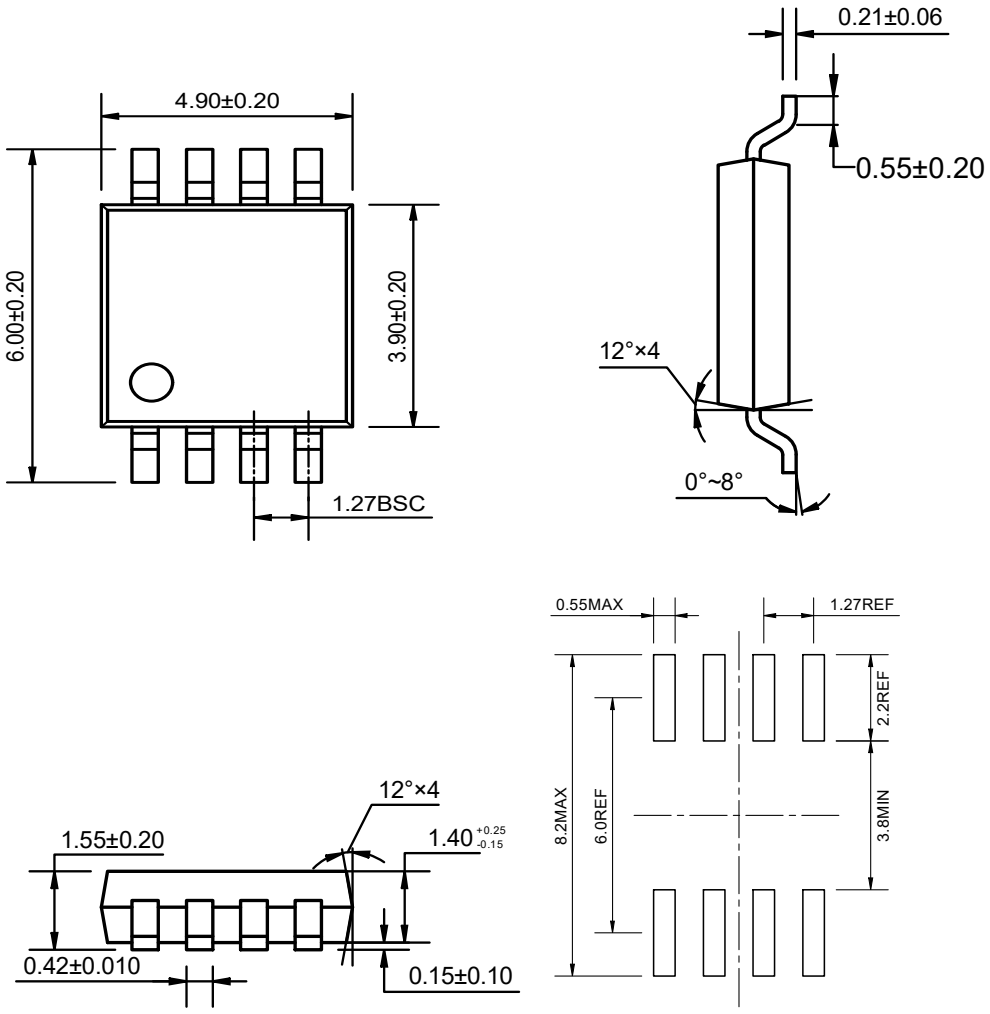
Place the external components as close to the device as possible. This configuration prevents parasitic errors (such as the Seebeck effect) from occurring.

To reduce parasitic coupling, run the input traces as far away from the supply lines and digital signal as possible.Low-ESR, 0.1 μF ceramic bypass capacitors must be connected between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable to single supply applications.

Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

Package Dimension

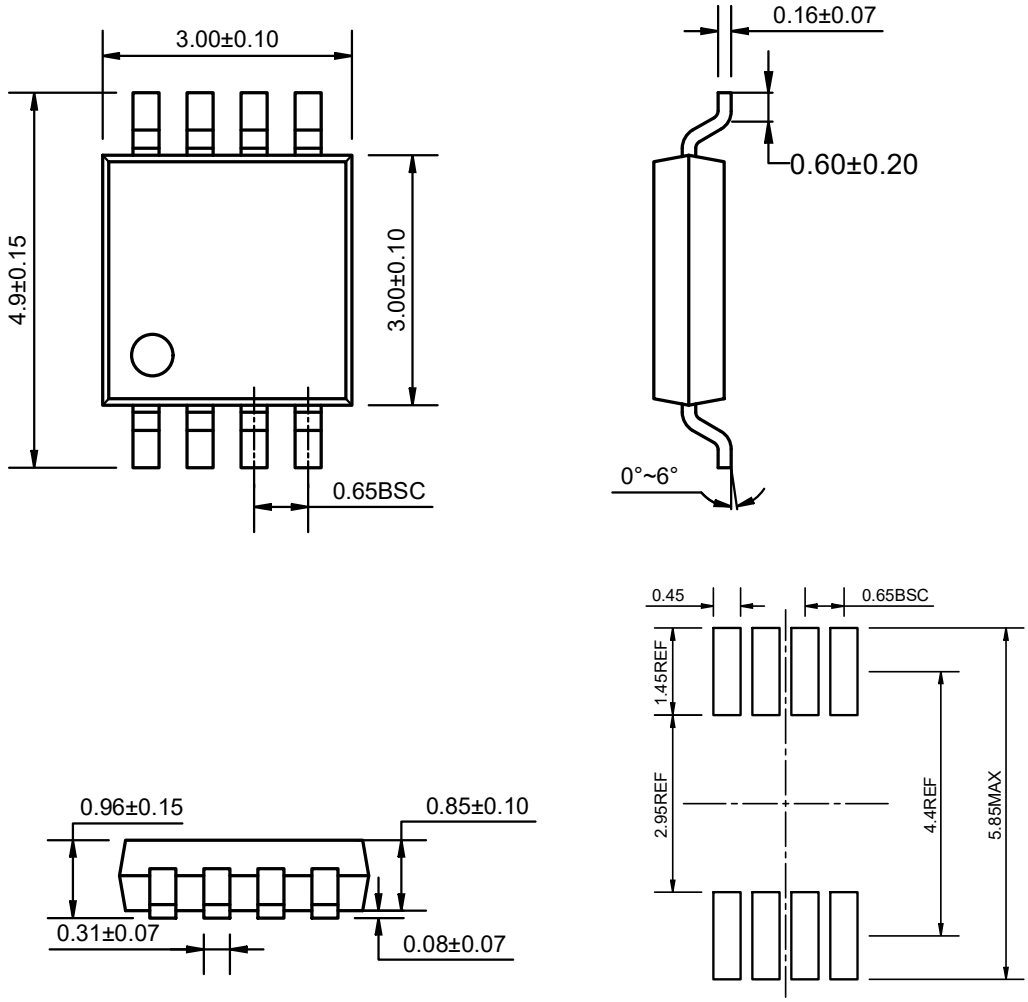
SOP8



Recommended Land Pattern

Unit: mm

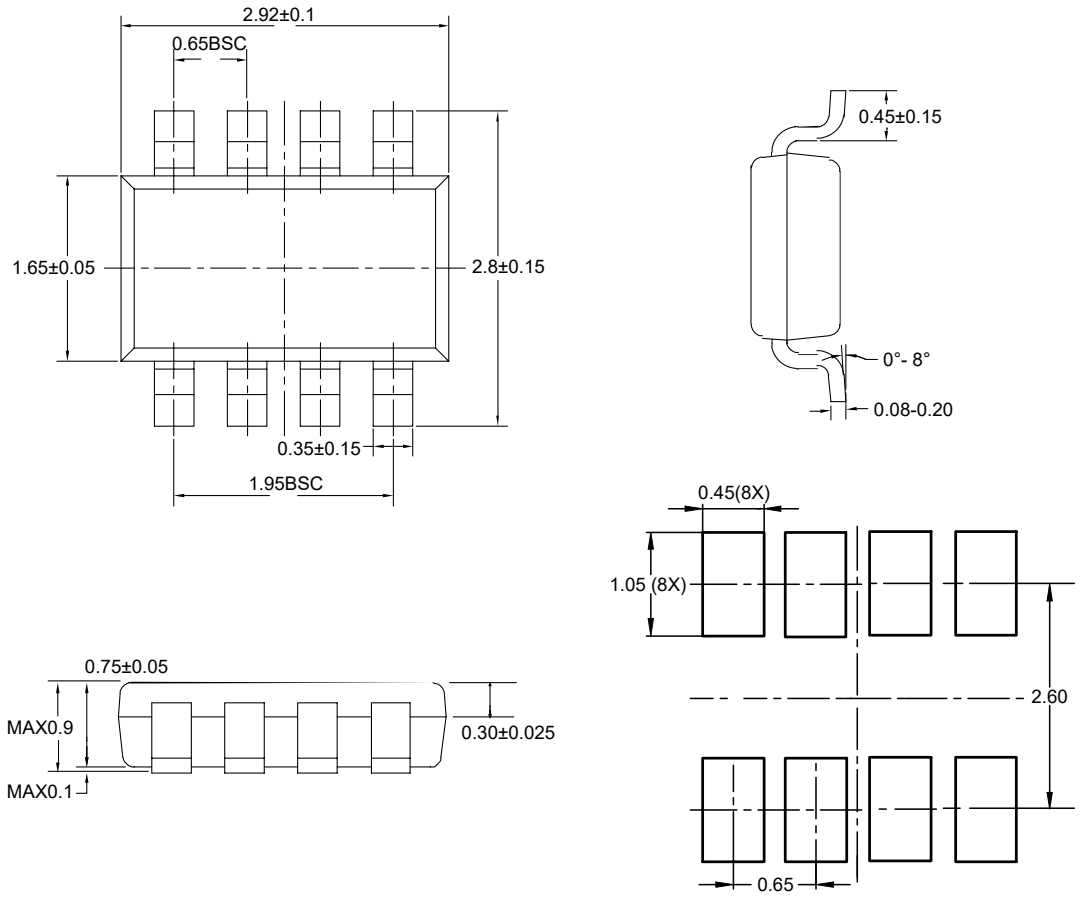
MSOP8



Recommended Land Pattern

Unit: mm

TSOT23-8



Recommended Land Pattern

Unit: mm

Revision History and Checking Table

Version	Date	RevisionItem	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2023-04-21	Preliminary Version	Huyt	Wanggp	Liujy
1.0	2023-08-31	Original Version	Huyt	Chenh	Liujy
1.1	2023-9-27	Naming updates	Shibo	Wanggp	Liujy
1.2	2023-10-19	Add TSOT23-8	Shibo	Wanggp	Liujy